



CS1210N3A

主要参数 MAIN CHARACTERISTICS

$I_{T(RMS)}$	12A
V_{DRM}	800V
I_{GT}	10mA

用途

- 交流开关
- 相位控制

APPLICATIONS

- AC switching
- Phase control

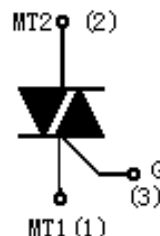
产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 低通态电流和高浪涌电流能力
- 环保 RoHS 产品

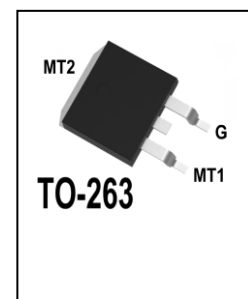
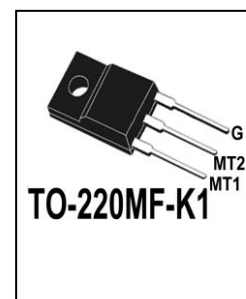
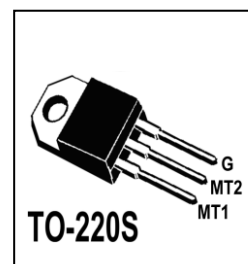
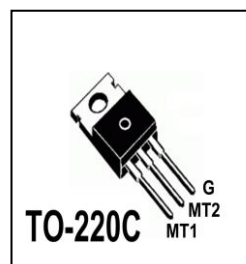
FEATURES

- Glass-passivated mesa chip for high reliability and uniform
- Low on-state voltage and High I_{TSM}
- RoHS products

封装 Package



序号 Pin	引线名称 Description
1	主电极 1 MT1
2	主电极 2 MT2
3	门极 G





订货信息 ORDER MESSAGES

订货型号 Order codes				印记 Marking	封装 Package
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装	CS1210N3A	TO-263
Halogen-Tube	halogen-Free-Tube	Halogen- Bag	Halogen-Free-Bag		
CS1210N3A-S-B	CS1210N3A-S-BR	CS1210N3A-S-C	CS1210N3A-S-CR		
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装	CS1210N3A	TO-220C
Halogen-Tube	halogen-Free-Tube	Halogen- Bag	Halogen-Free-Bag		
CS1210N3A-C-B	CS1210N3A-C-BR	CS1210N3A-C-C	CS1210N3A-C-CR		
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装	CS1210N3A	TO-220S
Halogen-Tube	halogen-Free-Tube	Halogen- Bag	Halogen-Free-Bag		
CS1210N3A-CB-B	CS1210N3A-CB-BR	CS1210N3A-CB-C	CS1210N3A-CB-CR		
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装	CS1210N3A	TO-220MF-K1
Halogen-Tube	halogen-Free-Tube	Halogen- Bag	Halogen-Free-Bag		
CS1210N3A-F1-B	CS1210N3A-F1-BR	CS1210N3A-F1-C	CS1210N3A-F1-CR		
无卤-编带				CS1210N3A	TO-263
Halogen-Free-Reel					
CS1210N3A-S-AR					

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	试 验 条 件 Condition	数 值 Value	单 位 Unit
重复峰值断态电压 Repetitive peak off-state voltage	V_{DRM}		± 800	V
通态方均根电流 On-state RMS current	$I_{\text{T(RMS)}}$	full sine wave	12	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current	I_{TSM}	full sine wave, $t=20\text{ms}$	150	A
		full sine wave, $t=16.7\text{ms}$	161	A
	I^2t	$t=10\text{ms}$	112	A^2s
通态电流临界上升率 Repetitive rate of rise of on-state current after triggering	di/dt	$I_{\text{TM}}=12\text{A}$, $I_{\text{G}}=0.2\text{A}$, $di_{\text{G}}/dt=0.2\text{A}/\mu\text{s}$	100	$\text{A}/\mu\text{s}$
峰值门极电流 Peak gate current	I_{GM}		2	A
峰值门极电压 Peak gate voltage	V_{GM}		5	V
峰值门极功率 Peak gate power	P_{GM}		5	W
平均门极功率 Average gate power	$P_{\text{G(AV)}}$	over any 20ms period	0.5	W
存储温度 Storage temperature	T_{stg}		-40~150	$^{\circ}\text{C}$
操作结温 Operation junction temperature	T_{VJ}		125	$^{\circ}\text{C}$



电特性 ELECTRICAL CHARACTERISTIC ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	测 试 条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
峰值重复断态电流 Peak Repetitive Blocking Current	I_{DRM}	$V_{\text{DM}}=V_{\text{DRM}}$, $T_j=125^\circ\text{C}$, gate open	-	0.2	0.8	mA
峰值通态电压 Peak on-state voltage	V_{TM}	$I_{\text{TM}}=10\text{A}$	-		1.65	V
门极触发电压 Gate trigger voltage	V_{GT}	$V_{\text{DM}}=12\text{V}$, $R_L=100\ \Omega$	-	-	1.5	V
门极开通时间 Gate controlled turn-on time	tgt	$I_{\text{TM}}=12\text{A}$, $V_{\text{DM}}=V_{\text{DRM(MAX)}}$, $I_G=0.1\text{A}$, $dI_G/dt=5\text{A}/\mu\text{S}$	-	2	-	μS
门极触发电流 Gate trigger current	I_{GT}	$V_{\text{DM}}=12\text{V}$, $R_L=100\ \Omega$	≤ 10			mA
		MT1(-), MT2(+), G(+)				mA
		MT1(-), MT2(+), G(-)				mA
维持电流 Holding current	I_{H}	$V_{\text{DM}}=12\text{V}$, $I_{\text{GT}}=0.1\text{A}$	≤ 25			mA
擎住电流 Latching current	I_{L}	$V_{\text{DM}}=12\text{V}$, $I_{\text{GT}}=0.1\text{A}$	≤ 50			mA
断态临界电压上升率 Rise of off- state voltage	dV/dt	$V_{\text{DM}}=67\% V_{\text{DRM(MAX)}}$, $T_j=125^\circ\text{C}$, gate open	40	-	-	$\text{V}/\mu\text{S}$

热特性 THERMAL CHARACTERISTIC

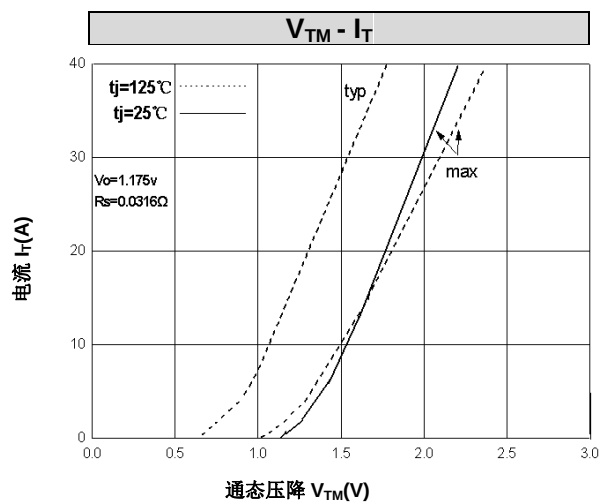
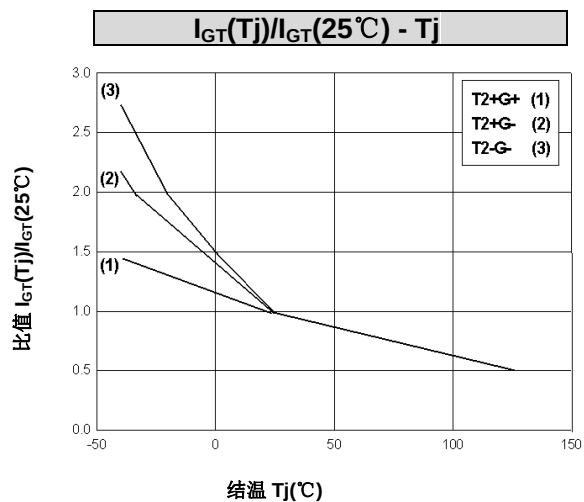
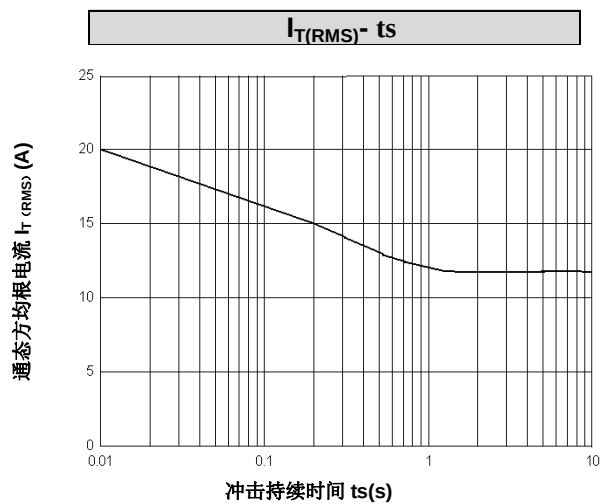
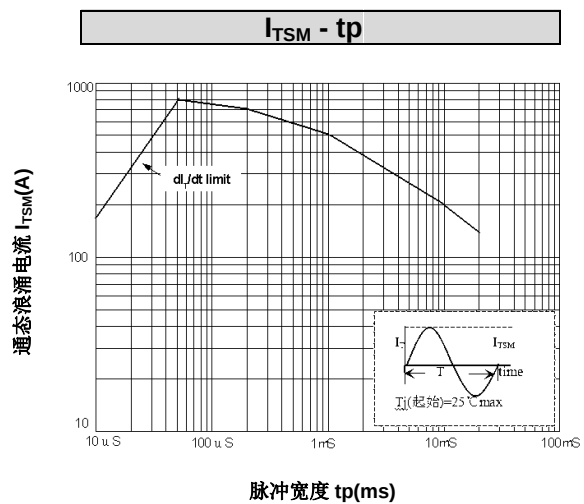
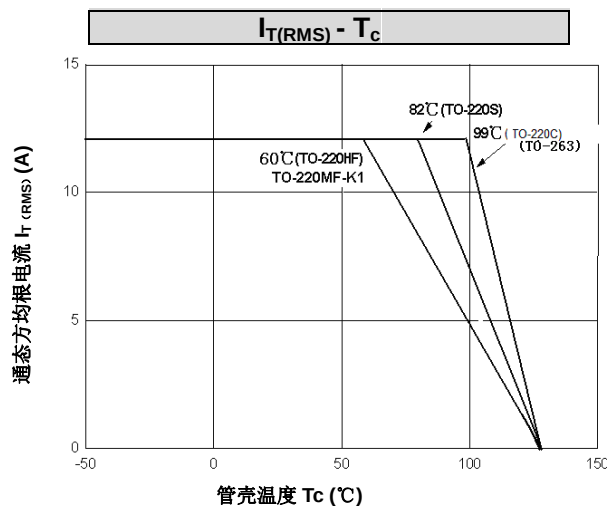
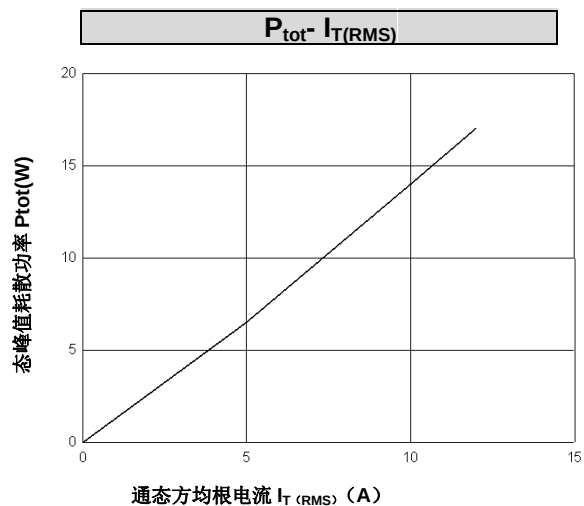
项 目 Parameter	符 号 Symbol	条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	$R_{\text{th(j-c)}}$	full cycle(TO-220MF-K1)			4.0	$^\circ\text{C}/\text{W}$
		full cycle(TO-220S)			2.4	$^\circ\text{C}/\text{W}$
		full cycle(TO-220C/TO-263)			1.5	$^\circ\text{C}/\text{W}$

电绝缘特性 ELECTRICAL ISOLATION

项 目 Parameter	符 号 Symbol	条 件 Condition	数 值 Value	单位 Unit
绝缘电压 Isolation voltage	V_{ISOL}	1 minute, leads to mounting tab TO-220MF-K1	2000	V



特征曲线 ELECTRICAL CHARACTERISTICS (curves)

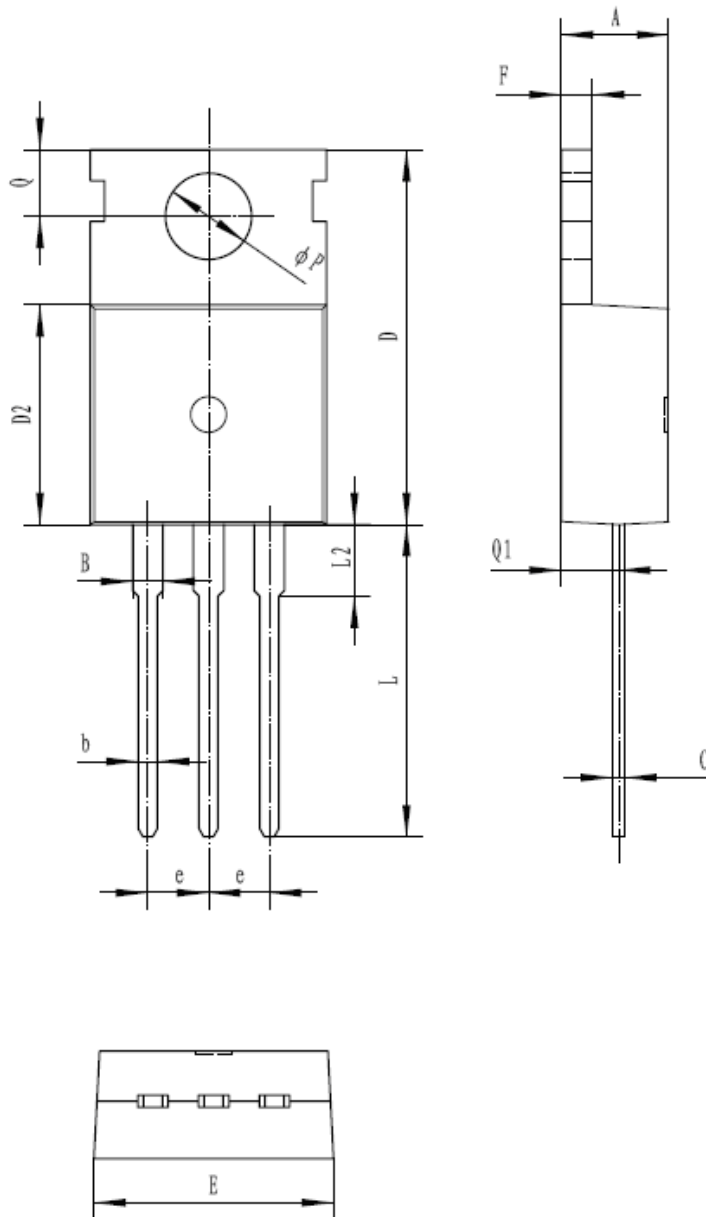




外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit : mm



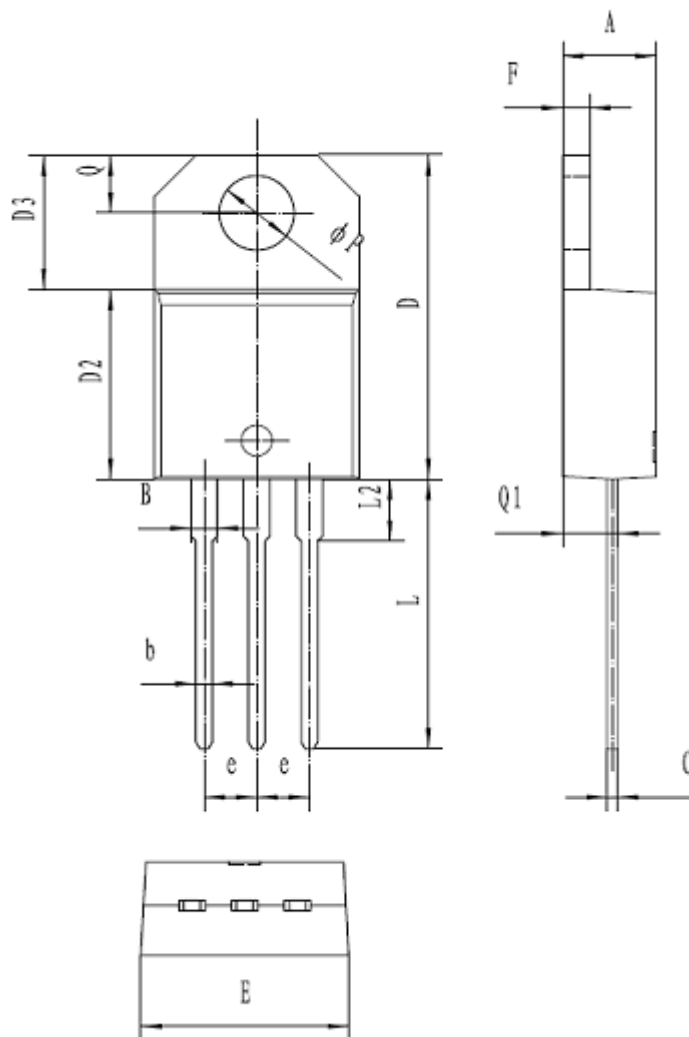
符号 symbol	MIN	MAX
A	4.30	4.70
B	1.22	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80



外形尺寸 PACKAGE MECHANICAL DATA

TO-220S

单位 Unit : mm



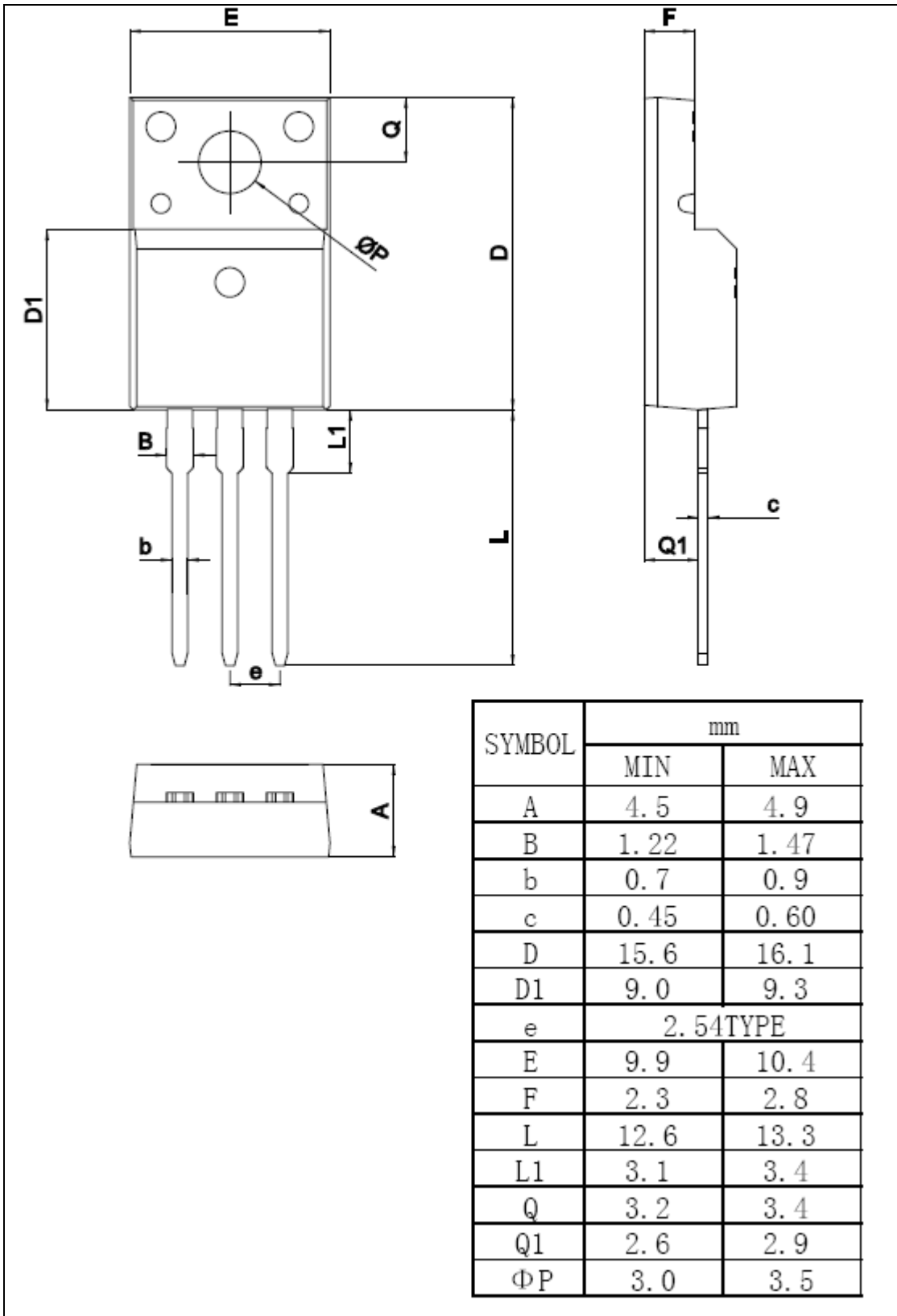
符号 symbol	MIN	MAX
A	4.40	4.60
B	1.14	1.70
b	0.61	0.88
C	0.47	0.70
D	15.20	15.90
D2	8.60	9.70
D3	6.20	6.60
E	10.00	10.40
e	2.40	2.70
F	1.23	1.32
L	13.00	14.00
L2	typ. 3.75	
Q	2.65	2.95
Q1	2.89	3.42
P	3.72	3.85



外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K1

单位 Unit : mm



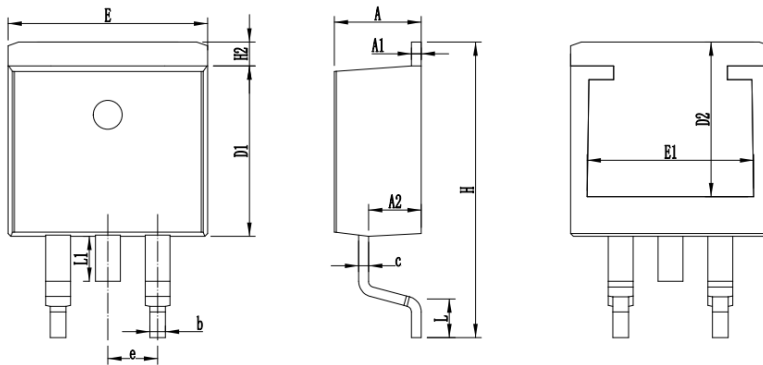


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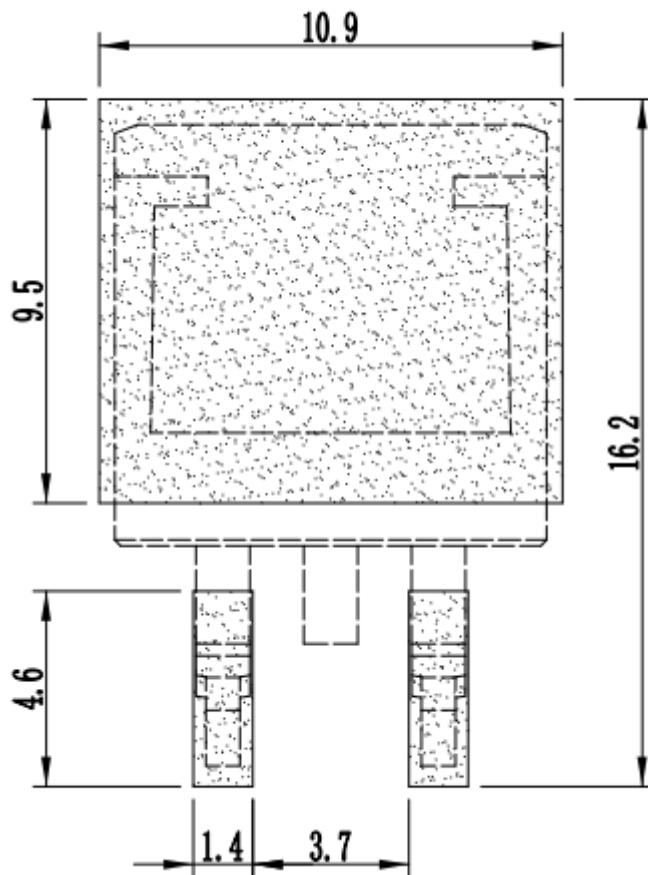
外形尺寸 PACKAGE MECHANICAL DATA

TO-263

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
D2	7.15	7.45
E	9.80	10.46
E1	7.65	8.15
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70





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